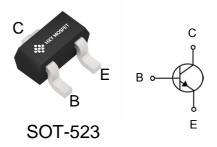


Features

- Collector Current: I_C= 2A
- Power Dissipation of 500mw

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
MMBT2222T/ MMBT2222AT	SOT-523	1P	3000



Maximum Ratings (Ta=25°C unless otherwise noted)

Symbl	Parameter	Value	Unit	
Vсво	Callagter Daga Valtage	MMBT2222T	60	
V CBO	VCBO Collector-Base Voltage MMBT2222AT	75	V	
V050	/CEO Collector-Emitter Voltage MMBT2222T MMBT2222AT	MMBT2222T	30	
VCEO		40	V	
Veno	/EBO Emitter-Base Voltage	MMBT2222T	5	V
VEBO		MMBT2222AT	6	
Ic	Collector Current-Continuous		0.6	Α
Pc	Collector Power Dissipation		150	mW
Tj	Junction Temperature		150	$^{\circ}$
T _{stg}	Storage Temperature		-55-150	$^{\circ}$



Electrical Characteristics (Ta=25°C unless otherwise specified)

Parameter		Symbol	Min.	Max.	Unit
DC Current Gain at V_{CE} = 10 V, I_{C} = 0.1 mA at V_{CE} = 10 V, I_{C} = 1 mA at V_{CE} = 10 V, I_{C} = 10 mA at V_{CE} = 1 V, I_{C} = 150 mA at V_{CE} = 10 V, I_{C} = 150 mA at V_{CE} = 10 V, I_{C} = 500 mA	MMBT2222T MMBT2222AT	h _{FE} h _{FE} h _{FE} h _{FE} h _{FE}	35 50 75 50 100 30 40	- - - 300 -	
Collector Base Cutoff Current at $V_{CB} = 50 \text{ V}$ at $V_{CB} = 60 \text{ V}$	MMBT2222T MMBT2222AT	I _{CBO}		100 100	nA
Emitter Base Cutoff Current at V _{EB} = 3 V		I _{EBO}	ı	100	nA
Collector Base Breakdown Voltage at I _C = 10 μA	MMBT2222T MMBT2222AT	$V_{(BR)CBO}$	60 75		٧
Collector Emitter Breakdown Voltage at I _C = 10 mA	MMBT2222T MMBT2222AT	$V_{(BR)CEO}$	30 40	1 1	٧
Emitter Base Breakdown Voltage at I _E = 10 μA	MMBT2222T MMBT2222AT	$V_{(BR)EBO}$	5 6	-	V
Collector Emitter Saturation Voltage at I_C = 150 mA, I_B = 15 mA at I_C = 500 mA, I_B = 50 mA	MMBT2222T MMBT2222AT MMBT2222T MMBT2222AT	V _{CE(sat)}	- - -	0.4 0.3 1.6 1	V
Base Emitter Saturation Voltage at I_C = 150 mA, I_B = 15 mA at I_C = 500 mA, I_B = 50 mA	MMBT2222T MMBT2222AT MMBT2222T MMBT2222AT	$V_{BE(sat)}$	- 0.6 -	1.3 1.2 2.6 2	V
Transition Frequency at $V_{CE} = 20 \text{ V}$, $I_E = 20 \text{ mA}$, $f = 100 \text{ MHz}$		f_{T}	300	ı	MHz
Collector Output Capacitance at V _{CB} = 10 V, f = 100 KHz		C_ob	-	8	pF
Delay Time at $V_{CC} = 30 \text{ V}$, $V_{BE(OFF)} = 0.5 \text{ V}$, $I_C = 150 \text{ mA}$., I _{B1} = 15 mA	t _d	-	10	ns
Rise Time at $V_{CC} = 30 \text{ V}$, $V_{BE(OFF)} = 0.5 \text{ V}$, $I_C = 150 \text{ mA}$., I _{B1} = 15 mA	t _r	-	25	ns
Storage Time at $V_{CC} = 30 \text{ V}$, $I_C = 150 \text{ mA}$, $I_{B1} = -I_{B2} = 15 \text{ m}$		t _{stg}	-	225	ns
Fall Time at V_{CC} = 30 V, I_C = 150 mA, I_{B1} = - I_{B2} = 15 mA		t _f	-	60	ns

Typical Characteristics

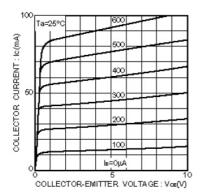


Fig.1 Grounded emitter output characteristics

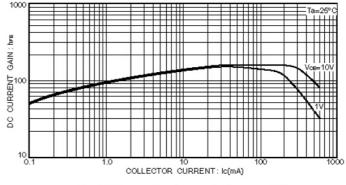


Fig.3 DC current gain vs. collector current(I)

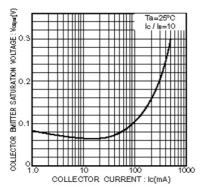


Fig.2 Gollector-emitter saturation voltage vs. collector current

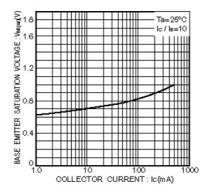
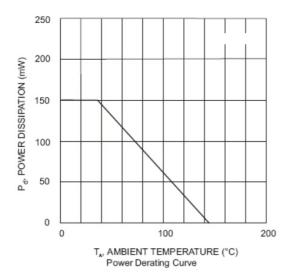


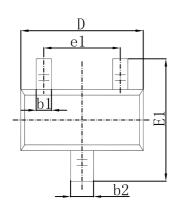
Fig.6 Base-emitter saturation voltage vs. collector current

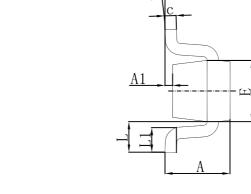


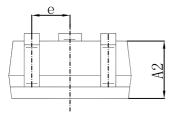


Package Dimensions

SOT-523

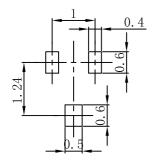






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	0.700	0.900	0.028	0.035	
A1	0.000	0.100	0.000	0.004	
A2	0.700	0.800	0.028	0.031	
b1	0.150	0.250	0.006	0.010	
b2	0.250	0.350	0.010	0.014	
С	0.100	0.200	0.004	0.008	
D	1.500	1.700	0.059	0.067	
E	0.700	0.900	0.028	0.035	
E1	1.450	1.750	0.057	0.069	
е	0.500	TYP.	0.020 TYP.		
e1	0.900	1.100	0.035	0.043	
L	0.400 REF.		0.016 REF.		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

Suggested Pad Layout



- 1.Controlling dimension:in millimeters.
 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

MMBT2222T / MMBT2222AT NPN Plastic-Encapsulate Transistors

Attention

- Any and all HUA XUAN YANG ELECTRONICS products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your HUA XUAN YANG ELECTRONICS representative nearest you before using any HUA XUAN YANG ELECTRONICS products described or contained herein in such applications.
- HUA XUAN YANG ELECTRONICS assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein.
- Specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- HUA XUAN YANG ELECTRONICS CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all HUA XUAN YANG ELECTRONICS products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of HUA XUAN YANG ELECTRONICS CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.

 HUA XUAN YANG ELECTRONICS believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc.

 When designing equipment, refer to the "Delivery Specification" for the HUA XUAN YANG ELECTRONICS product that you intend to use.